

04/25/00

ISSUE CLASSIFICATION	
Class	Subclass

PATENT NUMBER

U.S. **UTILITY** Patent Application

BP Q.I.P.E. SCANNED <i>rk</i> G.A. <i>WSD</i>	PATENT DATE
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APPLICATION NO. 09/557961	CONT/PRIOR F	CLASS 427 257	SUBCLASS 27 43	ART UNIT 1762 2811	EXAMINER ICANG Thompson
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TS Kunihiro Takatani

APPLICANTS

TITLE

Electrode structure on P-type III group nitride semiconductor layer
and formation method thereof

PTO-2040
12/99**ISSUING CLASSIFICATION**

ISSUING CLASSIFICATION												
ORIGINAL				CROSS REFERENCE(S)								
CLASS		SUBCLASS		CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)							
INTERNATIONAL CLASSIFICATION												

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<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS		CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	_____ (Assistant Examiner)		NOTICE OF ALLOWANCE MAILED _____	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____ _____ _____	_____ (Primary Examiner)		ISSUE FEE Amount Due Date Paid	
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<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	_____ (Date)		_____	

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